

# DC COMPONENTS CO., LTD.

### DISCRETE SEMICONDUCTORS

DCR100-3 **THRU** DCR100-8

TECHNICAL SPECIFICATIONS OF SENSITIVE GATE SILICON CONTROLLED RECTIFIERS VOLTAGE RANGE - 100 to 600 Volts **CURRENT - 0.8 Ampere** 

# Description

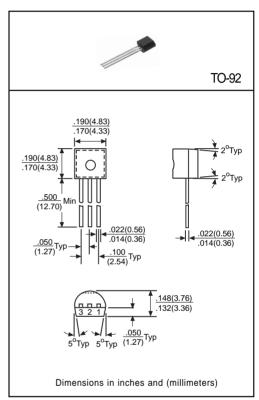
- \* Driven directly with IC and MOS device
- \* Feature proprietary, void-free glass passivated chips
- \* Available in voltage ratings from 100 to 600 volts
- \* Sensitive gate trigger current
- \* Designed for high volume, line-powered control application in relay lamp drivers, small motor controls, gate drivers for large thyristors

#### **Pinning**

1 = Cathode, 2 = Gate, 3 = Anode

## Absolute Maximum Ratings(TA=25°C)

Characteristic		Symbol	Rating	Unit
Peak Repetitive Off-State Voltage and Reverse Voltage	DCR100-3 DCR100-4 DCR100-6 DCR100-8	Vdrm, Vrrm	100 200 400 600	V
On-State RMS Current (Ta=57°C, 180° Conduction And	IT(RMS)	0.8	Α	
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60Hz)		Ітѕм	8	Α
Forward Peak Gate Current(For 3µ sec.)		lgм	0.8	Α
Forward Peak Gate Power Dissipation		Рсм	0.1	W
Forward Average Gate Power D	PG(AV)	0.01	W	
Reverse Peak Gate Voltage	VGRM	6.0	V	
Operating Junction Temperature	TJ	-40 to +110	°C	
Storage Temperature		Тѕтс	-40 to +150	°C



Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified)

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Characteristic		Symbol	Min	Тур	Max	Unit	Test Conditions
Peak Repetitive Forward or Reverse Off-State Blocking Current	T <sub>A</sub> =25°C	IDRM, IRRM	-	-	10	μΑ	Vak=Rated Vdrm or Vrrm Rgk=1KΩ
	T <sub>A</sub> =125°C		-	-	200		
Peak Forward On-State Voltage		Vтм	-	-	1.7	٧	Ітм=0.8A Peak, Tc=25°C
Continuous DC Gate Trigger Current		lgт	-	-	200	μА	Vak=7V DC, RL=100Ω
Continuous DC Gate Trigger Voltage		Vgt	-	-	0.8	٧	Vak=7V DC, RL=100Ω
DC Holding Current		lн	-	-	10	mA	Rgκ=1KΩ, Gate Open
Critical Rate-of-Rise of Off-State Voltage		dv/dt	-	5	-	V/μS	Rgκ=1KΩ, Gate Open
Gate Controlled Turn-on Time(tD+tR)		Tgt	-	2.2	-	μsec	Igт=10mA
Thermal Resistance, Junction to Case		Rejc	-	75	-	°C/W	-